



30V P-Channel Enhancement Mode MOSFET

Voltage -30 V Current -4.6A

Features

- RDS(ON) , VGS@-10V, ID@-4.6A<72mΩ
- RDS(ON) , VGS@-4.5V, ID@-3.0A<96mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

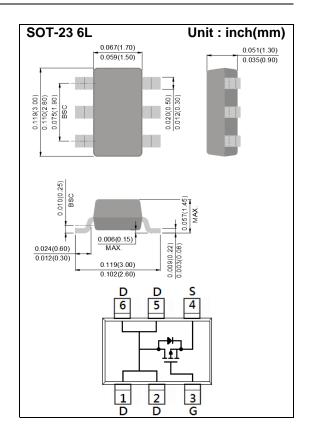
Mechanical Data

• Case: SOT-23 6L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.0005 ounces, 0.014 grams

Marking: S05



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V _G s	<u>+</u> 20	V
Continuous Drain Current		I _D	-4.6	Α
Pulsed Drain Current		I _{DM}	-18.4	Α
Power Dissipation	T _a =25°C	P _D	2	W
	Derate above 25°C		16	mW/°C
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C
Typical Thermal Resistance				
- Junction to Ambient ^(Note 3)		$R_{ heta JA}$	62.5	°C/W





Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-1	-1.38	-2.1	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-4.6A	-	61	72	mΩ
		V _{GS} =-4.5V, I _D =-3.0A	-	78	96	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-0.01	-1	uA
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 20V, V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Dynamic						
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =-4.6A, V _{GS} =-10V ^(Note 1,2)	-	5.2	-	nC
Gate-Source Charge	Q_{gs}		-	1.3	-	
Gate-Drain Charge	Q_gd		-	1.9	-	
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	417	-	pF
Output Capacitance	Coss		-	50	-	
Reverse Transfer Capacitance	Crss		-	36	-	
Switching						
Turn-On Delay Time	td _(on)	V_{DD} =-15V, I_{D} =-4.6A, V_{GS} =-10V, R_{G} =6 $\Omega^{(Note\ 1,2)}$	-	3.5	-	ns
Turn-On Rise Time	tr		-	34	-	
Turn-Off Delay Time	td _(off)		-	120	-	
Turn-Off Fall Time	tf		-	71	-	
Drain-Source Diode						
Maximum Continuous Drain-Source	Is		-	-	-2.0	А
Diode Forward Current						
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _G S=0V	-	-0.74	-1.2	V

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

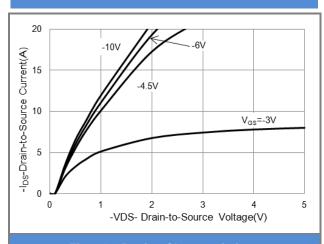


Fig.1 On-Region Characteristics

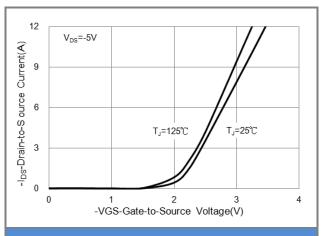


Fig.2 Transfer Characteristics

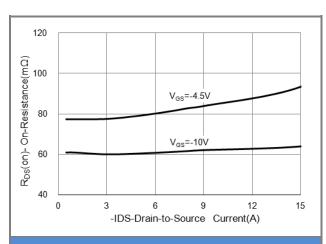


Fig.3 On-Resistance vs. Drain Current

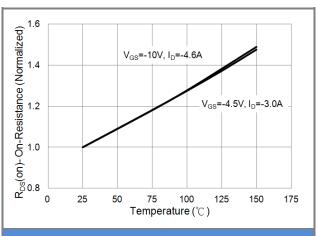
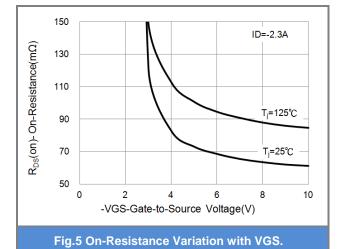


Fig.4 On-Resistance vs. Junction temperature



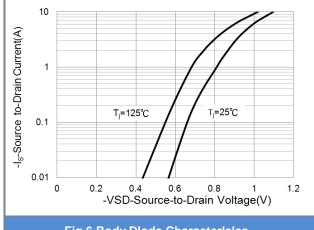


Fig.6 Body Dlode CharacterIslcs





TYPICAL CHARACTERISTIC CURVES

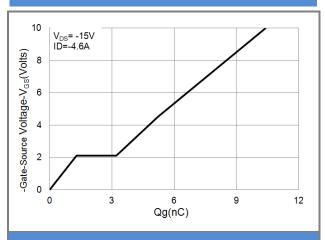


Fig.7 Gate-Charge Characteristics

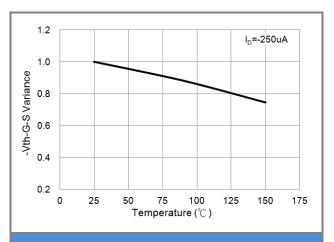


Fig.8 Threshold Voltage Variation with Temperature.

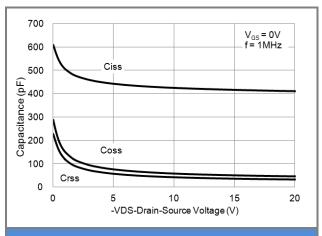


Fig.9 Capacitance vs. Drain-Source Voltage.

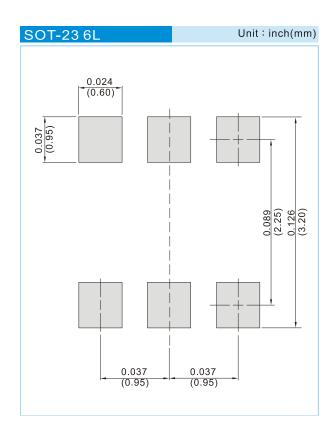




PART NO. PACKING CODE VERSION

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJS6405_S1_00001	SOT-23 6L	3K pcs / 7" reel	S05	Halogen free RoHS compliant
PJS6405_S2_00001	SOT-23 6L	10K pcs / 13" reel	S05	Halogen free RoHS compliant

MOUNTING PAD LAYOUT







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